

PMV27UPE 20 V, P-channel Trench MOSFET 15 May 2014

Product data sheet

1. General description

P-channel enhancement mode Field-Effect Transistor (FET) in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- Trench MOSFET technology
- Low threshold voltage
- Very fast switching
- Enhanced power dissipation capability: P_{tot} = 980 mW
- ElectroStatic Discharge (ESD) protection 2 kV HBM

3. Applications

- LED driver
- Power management
- High-side loadswitch
- Switching circuits

4. Quick reference data

Table 1. Qui	ck reference data						
Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-	-20	V
V _{GS}	gate-source voltage	_		-8	-	8	V
I _D	drain current	V_{GS} = -4.5 V; T_{amb} = 25 °C; t ≤ 5 s	[1]	-	-	-5.6	А
Static characteristics							
R _{DSon}	drain-source on-state resistance	V _{GS} = -4.5 V; I _D = -4.5 A; T _j = 25 °C		-	27	32	mΩ

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm².



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5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate	3	D
2	S	source		
3	D	drain	1 2 TO-236AB (SOT23)	G S 017aaa259

6. Ordering information

Table 3. Ordering information					
Type number Package					
	Name	Description	Version		
PMV27UPE	TO-236AB	plastic surface-mounted package; 3 leads	SOT23		

7. Marking

Table 4. Marking codes	
Type number	Marking code
	[1]
PMV27UPE	%KD

[1] % = placeholder for manufacturing site code

8. Limiting values

Table 5.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-20	V
V _{GS}	gate-source voltage			-8	8	V
I _D	drain current	V_{GS} = -4.5 V; T_{amb} = 25 °C; t ≤ 5 s	[1]	-	-5.6	А
		V _{GS} = -4.5 V; T _{amb} = 25 °C	[1]	-	-4.5	А
		V _{GS} = -4.5 V; T _{amb} = 100 °C	[1]	-	-2.8	А
I _{DM}	peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	-18	А
P _{tot}	total power dissipation	T _{amb} = 25 °C	[2]	-	490	mW

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Symbol	Parameter	Conditions		Min	Max	Unit
			[1]	-	980	mW
		T _{sp} = 25 °C		-	4150	mW
Tj	junction temperature			-55	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C
Source-drain diode						
I _S	source current	T _{amb} = 25 °C	[1]	-	-1.2	А

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm².

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

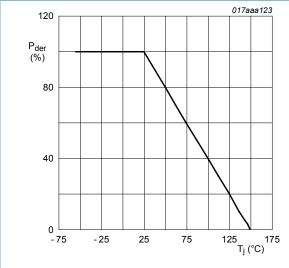


Fig. 1. Normalized total power dissipation as a function of junction temperature

$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100 \%$$

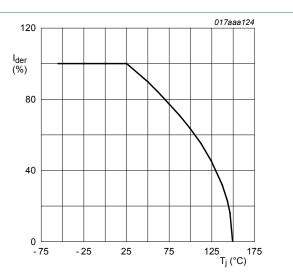
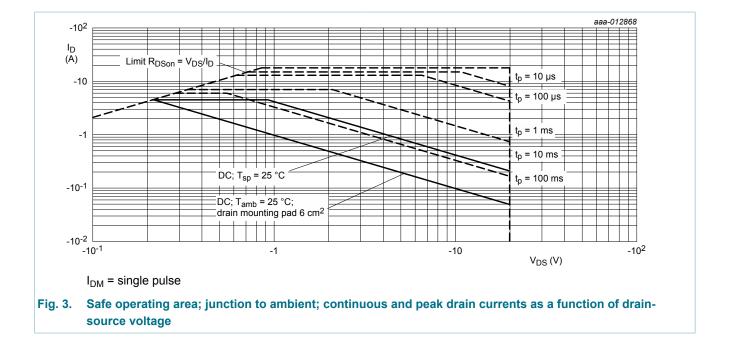


Fig. 2. Normalized continuous drain current as a function of junction temperature

$$I_{der} = \frac{I_D}{I_{D(25^\circ\text{C})}} \times 100 \%$$

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9. Thermal characteristics

Table 6. T	hermal characteristics						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)} thermal resistar from junction to ambient	thermal resistance	-	[1]	-	222	255	K/W
	-		[2]	-	111	128	K/W
	ambient	in free air; t ≤ 5 s	[2]	-	74	85	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	25	30	K/W

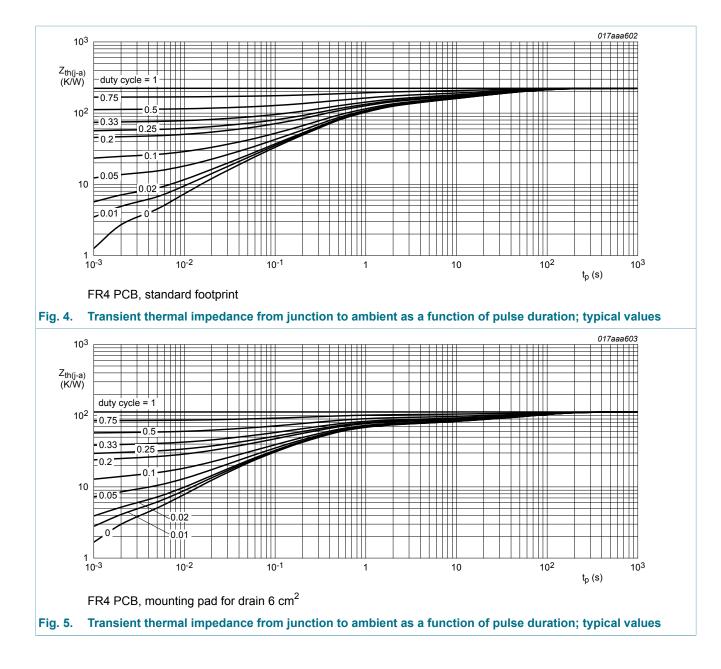
[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm².

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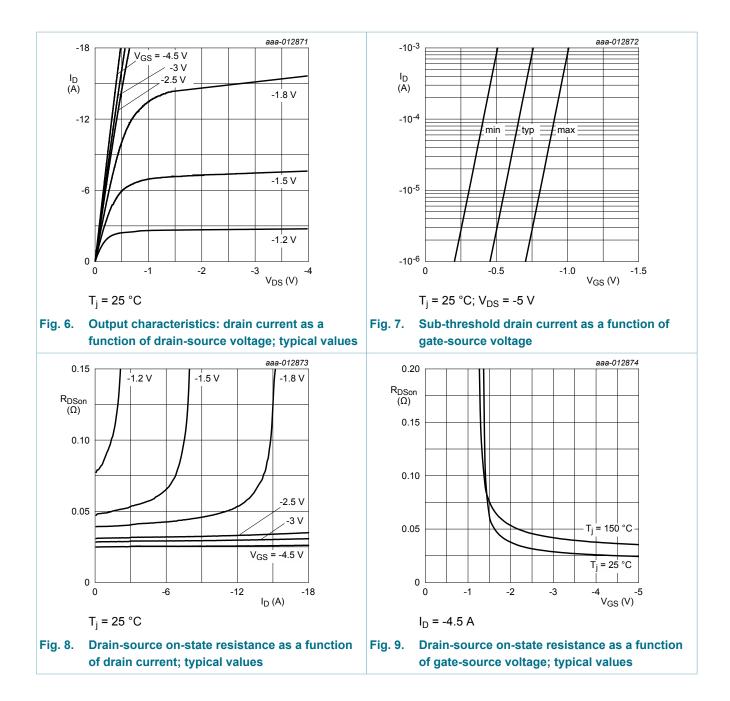
10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	octeristics					
V _{(BR)DSS}	drain-source breakdown voltage	I_D = -250 µA; V_{GS} = 0 V; T_j = 25 °C	-20	-	-	V
V _{GSth}	gate-source threshold voltage	I_D = -250 µA; V_{DS} = V_{GS} ; T_j = 25 °C	-0.45	-0.7	-0.95	V
I _{DSS}	drain leakage current	V _{DS} = -20 V; V _{GS} = 0 V; T _j = 25 °C	-	-	-1	μA
I _{GSS} gate lea	gate leakage current	V _{GS} = 8 V; V _{DS} = 0 V; T _j = 25 °C	-	-	10	μA
		V_{GS} = -8 V; V_{DS} = 0 V; T_j = 25 °C	-	-	-10	μA
		V_{GS} = 4.5 V; V_{DS} = 0 V; T_j = 25 °C	-	-	5	μA
		V_{GS} = -4.5 V; V_{DS} = 0 V; T_j = 25 °C	-	-	-5	μA
R _{DSon} drain-source on-state resistance	V_{GS} = -4.5 V; I _D = -4.5 A; T _j = 25 °C	-	27	32	mΩ	
	resistance	V_{GS} = -4.5 V; I _D = -4.5 A; T _j = 150 °C	-	40	48	mΩ
		V_{GS} = -2.5 V; I _D = -3.8 A; T _j = 25 °C	-	38	45	mΩ
	V _{GS} = -1.8 V; I _D = -3 A; T _j = 25 °C	-	50	63	mΩ	
9 _{fs}	forward transconductance	V _{DS} = -10 V; I _D = -2 A; T _j = 25 °C	-	15	-	S
R _G	gate resistance	f = 1 MHz	-	10.7	-	Ω
Dynamic ch	aracteristics		I			
Q _{G(tot)}	total gate charge	V_{DS} = -10 V; I _D = -4.4 A; V _{GS} = -4.5 V;	-	14.7	22.1	nC
Q _{GS}	gate-source charge	T _j = 25 °C	-	2.6	-	nC
Q _{GD}	gate-drain charge		-	2.5	-	nC
C _{iss}	input capacitance	V_{DS} = -10 V; f = 1 MHz; V_{GS} = 0 V;	-	1820	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	208	-	pF
C _{rss}	reverse transfer capacitance		-	146	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = -10 V; I _D = -4.4 A; V _{GS} = -4.5 V;	-	11	-	ns
t _r	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C$	-	30	-	ns
t _{d(off)}	turn-off delay time		-	83	-	ns
t _f	fall time		-	39	-	ns
Source-drai	n diode	· · · · · · · · · · · · · · · · · · ·	I			
V _{SD}	source-drain voltage	I _S = -1.2 A; V _{GS} = 0 V; T _i = 25 °C	-	-0.7	-1.2	V

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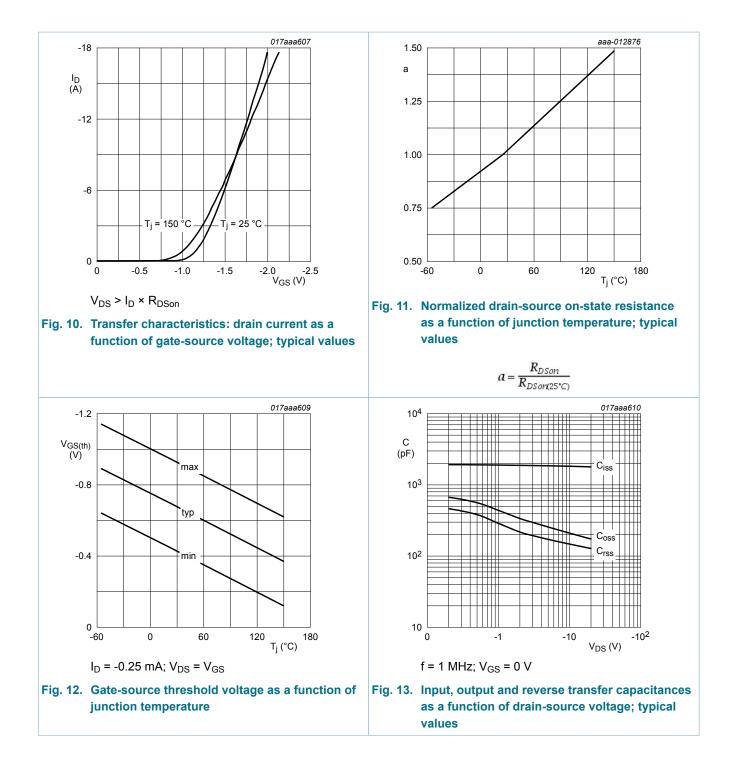
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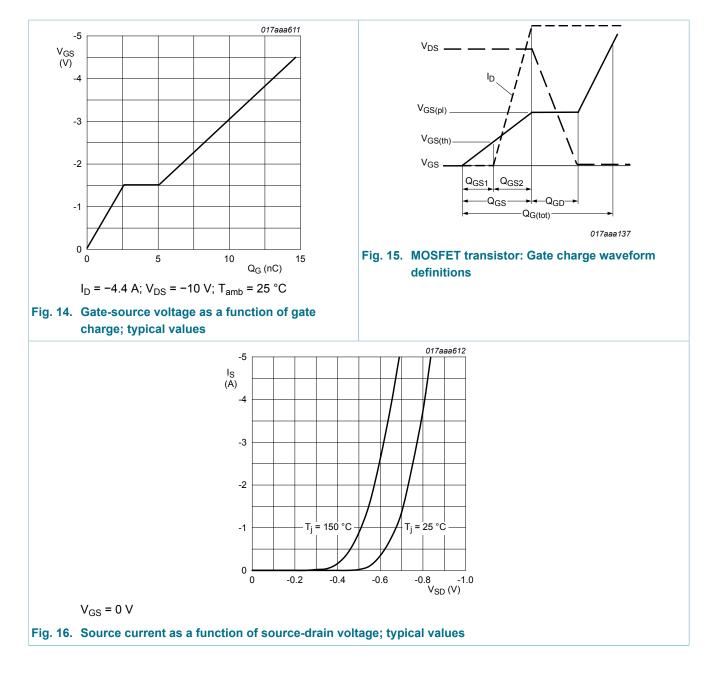
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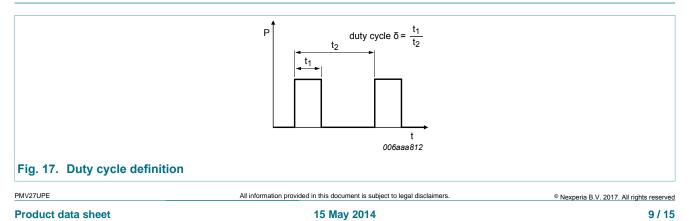


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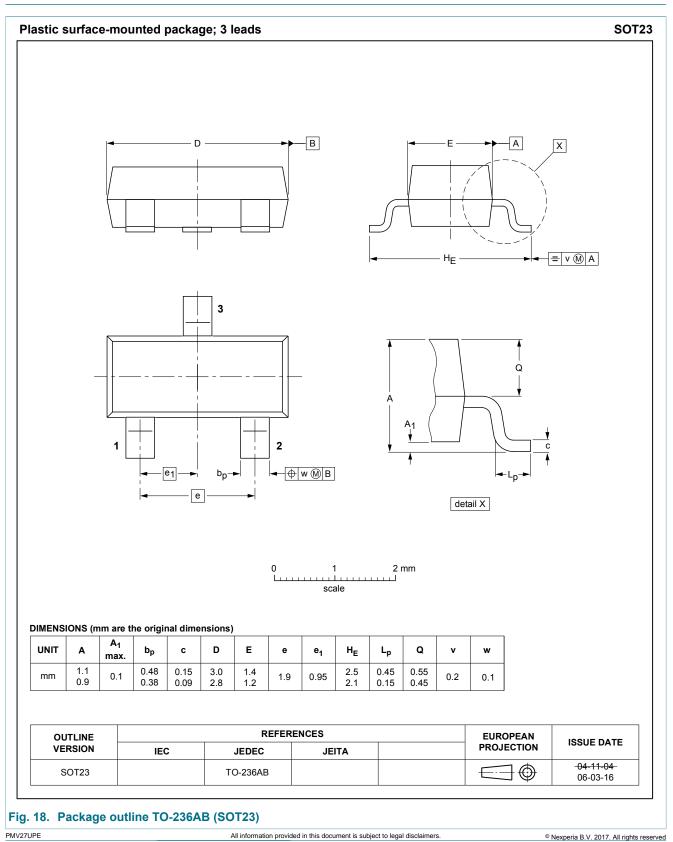


11. Test information



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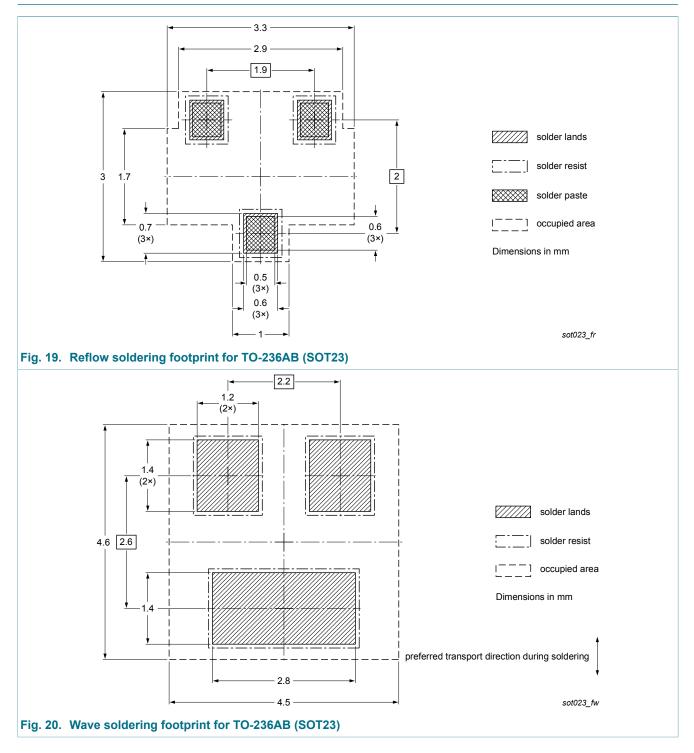
12. Package outline



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13. Soldering



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14. Revision history

Table 8. Revision his	able 8. Revision history					
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes		
PMV27UPE v.1	20140515	Product data sheet	-	-		

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15. Legal information

15.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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